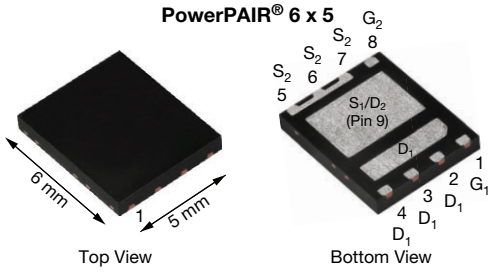
Dual N-Channel 30 V (D-S) MOSFET



FEATURES

- TrenchFET® power MOSFET
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

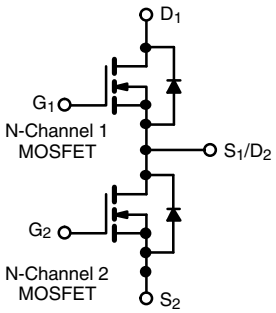
Pb-free

RoHS COMPLIANT

HALOGEN FREE

APPLICATIONS

- Notebook system power
- POL
- Synchronous buck converter



PRODUCT SUMMARY

	CHANNEL-1	CHANNEL-2
V_{DS} (V)	30	30
$R_{DS(on)}$ max. (Ω) at V_{GS} = 10 V	0.0120	0.0064
$R_{DS(on)}$ max. (Ω) at V_{GS} = 4.5 V	0.0145	0.0083
Q_g typ. (nC)	6.8	21
I_D (A) [a]	16	16
Configuration	Dual	

ORDERING INFORMATION

Package	PowerPAIR 6 x 5
Lead (Pb)-free and halogen-free	SiZ902DT-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	CHANNEL-1	CHANNEL-2	UNIT
Drain-source voltage		V_{DS}	30	30	V
Gate-source voltage		V_{GS}	± 20	± 20	
Continuous drain current (T_J = 150 °C)	T_C = 25 °C	I_D	16 [a]	16 [a]	A
	T_C = 70 °C		16 [a]	16 [a]	
	T_A = 25 °C		14.3 [b, c]	16 [a, b, c]	
	T_A = 70 °C		11.4 [b, c]	16 [a, b, c]	
Pulsed drain current (t = 300 µs)		I_{DM}	50	80	
Continuous source-drain diode current	T_C = 25 °C	I_S	16 [a]	16 [a]	
	T_A = 25 °C		3.4 [b, c]	4.1 [b, c]	
Single pulse avalanche current	L = 0.1 mH	I_{AS}	18	30	
Single pulse avalanche energy		E_{AS}	16	45	mJ
Maximum power dissipation	T_C = 25 °C	P_D	29	66	W
	T_C = 70 °C		18	42	
	T_A = 25 °C		4.2 [b, c]	5 [b, c]	
	T_A = 70 °C		2.7 [b, c]	3.2 [b, c]	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +150		°C
Soldering recommendations (peak temperature) [d, e]			260		

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	CHANNEL-1		CHANNEL-2		UNIT
			TYP.	MAX.	TYP.	MAX.	
Maximum junction-to-ambient [b, f]	t ≤ 10 s	R_{thJA}	24	30	20	25	°C/W
Maximum junction-to-case (drain)	Steady state	R_{thJC}	3.4	4.3	1.5	1.9	

Notes

a. Package limited
b. Surface mounted on 1" x 1" FR4 board
c. t = 10 s
d. See solder profile (www.vishay.com/doc?73257). The PowerPAIR is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
f. Maximum under steady state conditions is 65 °C/W for channel-1 and 57 °C/W for channel-2

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SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	Ch-1	30	-	-	V
			Ch-2	30	-	-	
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	I_D = 250 µA	Ch-1	-	33	-	mV/°C
			Ch-2	-	33	-	
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$		Ch-1	-	-5	-	
			Ch-2	-	-4.6	-	
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	Ch-1	1	-	2.2	V
			Ch-2	1	-	2.2	
Gate-source leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = +20 V	Ch-1	-	-	± 100	nA
			Ch-2	-	-	± 100	
Zero gate voltage drain current	I_{DSS}	V_{DS} = 30 V, V_{GS} = 0 V	Ch-1	-	-	1	µA
			Ch-2	-	-	1	
		V_{DS} = 30 V, V_{GS} = 0 V, T_J = 55 °C	Ch-1	-	-	5	
			Ch-2	-	-	5	
On-state drain current [b]	$I_{D(on)}$	$V_{DS} \geq$ 5 V, V_{GS} = 10 V	Ch-1	20	-	-	A
			Ch-2	20	-	-	
Drain-source on-state resistance [b]	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 13.8 A	Ch-1	-	0.0100	0.0120	Ω
		V_{GS} = 10 V, I_D = 20 A	Ch-2	-	0.0053	0.0064	
		V_{GS} = 4.5 V, I_D = 12.6 A	Ch-1	-	0.0120	0.0145	
		V_{GS} = 4.5 V, I_D = 20 A	Ch-2	-	0.0068	0.0083	
Forward transconductance [b]	g_{fs}	V_{DS} = 10 V, I_D = 13.8 A	Ch-1	-	47	-	S
		V_{DS} = 10 V, I_D = 20 A	Ch-2	-	63	-	
Dynamic [a]							
Input capacitance	C_{iss}	Channel-1 V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz	Ch-1	-	790	-	pF
			Ch-2	-	2600	-	
Output capacitance	C_{oss}		Ch-1	-	190	-	
		Channel-2 V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz	Ch-2	-	485	-	
Reverse transfer capacitance	C_{rss}		Ch-1	-	76	-	
			Ch-2	-	215	-	
Total gate charge	Q_g	V_{DS} = 15 V, V_{GS} = 10 V, I_D = 13.8 A	Ch-1	-	14	21	nC
		V_{DS} = 15 V, V_{GS} = 10 V, I_D = 20 A	Ch-2	-	43	65	
		V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 13.8 A	Ch-1	-	6.8	11	
		V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 20 A	Ch-2	-	21	32	
Gate-source charge	Q_{gs}	Channel-1 V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 13.8 A	Ch-1	-	2.6	-	
			Ch-2	-	8.1	-	
Gate-drain charge	Q_{gd}	Channel-2 V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 20 A	Ch-1	-	1.9	-	
			Ch-2	-	6.5	-	
Gate resistance	R_g	f = 1 MHz	Ch-1	0.4	2	-	Ω
			Ch-2	0.3	1.5	-	

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SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Dynamic [a]							
Turn-on delay time	$t_{d(on)}$	Channel-1 V_{DD} = 15 V, R_L = 1.5 Ω, $I_D \cong$ 10 A, V_{GEN} = 4.5 V, R_g = 1 Ω	Ch-1	-	15	30	ns
			Ch-2	-	23	50	
Rise time	t_r		Ch-1	-	12	20	
			Ch-2	-	20	40	
Turn-off delay time	$t_{d(off)}$	Channel-2 V_{DD} = 15 V, R_L = 1.5 Ω, $I_D \cong$ 10 A, V_{GEN} = 4.5 V, R_g = 1 Ω	Ch-1	-	20	40	
			Ch-2	-	35	70	
Fall time	t_f		Ch-1	-	10	20	
			Ch-2	-	10	20	
Turn-on delay time	$t_{d(on)}$	Channel-1 V_{DD} = 15 V, R_L = 1.5 Ω, $I_D \cong$ 10 A, V_{GEN} = 10 V, R_g = 1 Ω	Ch-1	-	10	20	
			Ch-2	-	22	25	
Rise time	t_r		Ch-1	-	12	20	
			Ch-2	-	10	20	
Turn-off delay time	$t_{d(off)}$	Channel-2 V_{DD} = 15 V, R_L = 1.5 Ω, $I_D \cong$ 10 A, V_{GEN} = 10 V, R_g = 1 Ω	Ch-1	-	20	40	
			Ch-2	-	35	70	
Fall time	t_f		Ch-1	-	10	20	
			Ch-2	-	10	20	
Drain-Source Body Diode Characteristics							
Continuous source-drain diode current	I_S	T_C = 25 °C	Ch-1	-	-	16	A
			Ch-2	-	-	16	
Pulse diode forward current [a]	I_{SM}		Ch-1	-	-	50	
			Ch-2	-	-	80	
Body diode voltage	V_{SD}	I_S = 10 A, V_{GS} = 0 V	Ch-1	-	0.85	1.2	V
			Ch-2	-	0.8	1.2	
Body diode reverse recovery time	t_{rr}	Channel-1 I_F = 10 A, di/dt = 100 A/µs, T_J = 25 °C	Ch-1	-	20	40	ns
			Ch-2	-	25	50	
Body diode reverse recovery charge	Q_{rr}		Ch-1	-	10	20	nC
			Ch-2	-	13	25	
Reverse recovery fall time	t_a	Channel-2 I_F = 10 A, di/dt = 100 A/µs, T_J = 25 °C	Ch-1	-	11	-	ns
			Ch-2	-	12	-	
Reverse recovery rise time	t_b		Ch-1	-	9	-	
			Ch-2	-	13	-	

Notes

a. Guaranteed by design, not subject to production testing

b. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

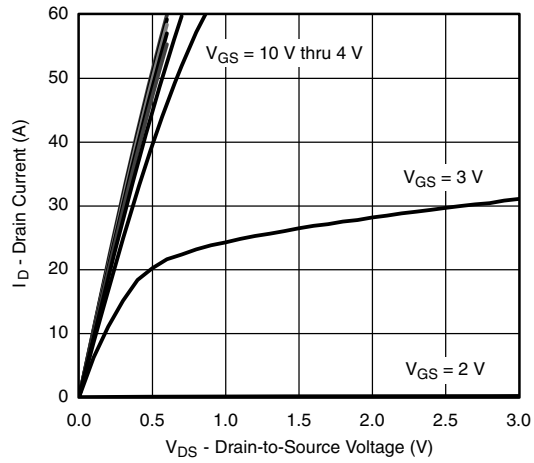
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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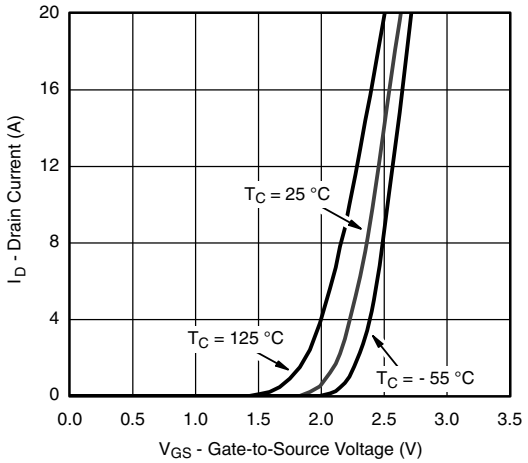
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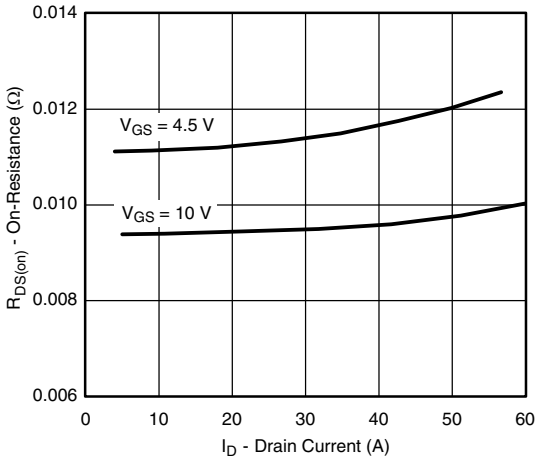
CHANNEL-1 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



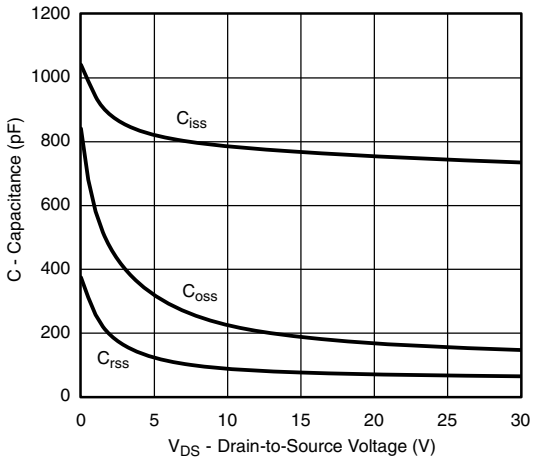
Output Characteristics



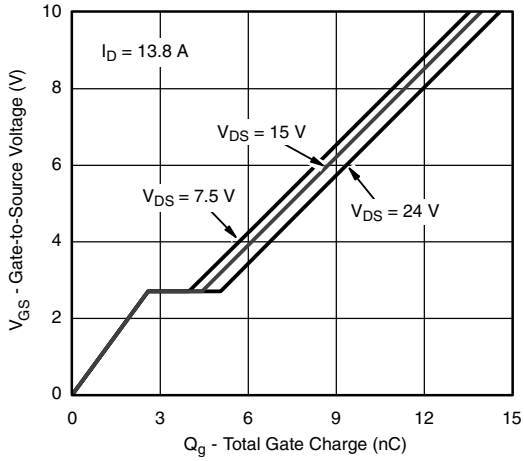
Transfer Characteristics



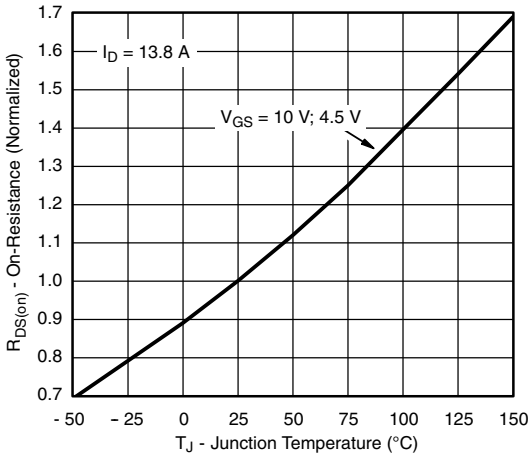
On-Resistance vs. Drain Current



Capacitance



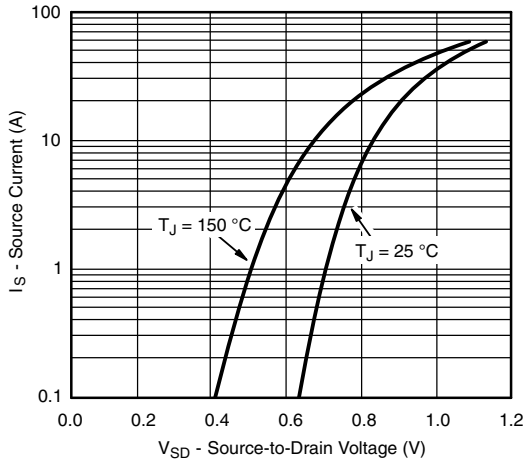
Gate Charge



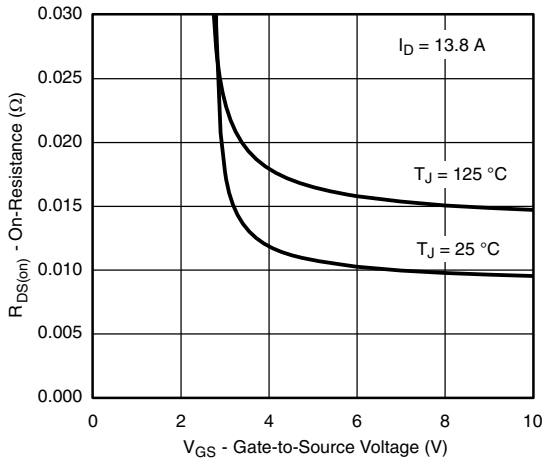
On-Resistance vs. Junction Temperature

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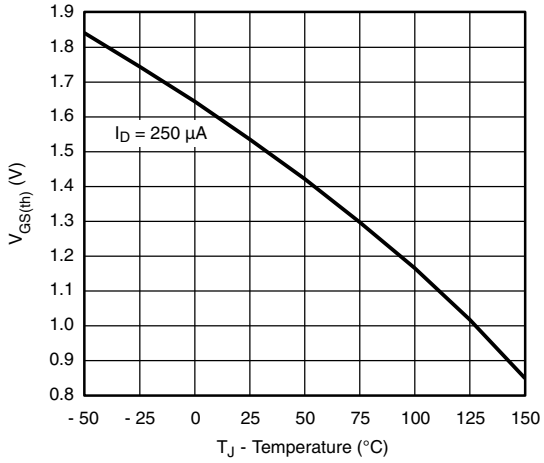
CHANNEL-1 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



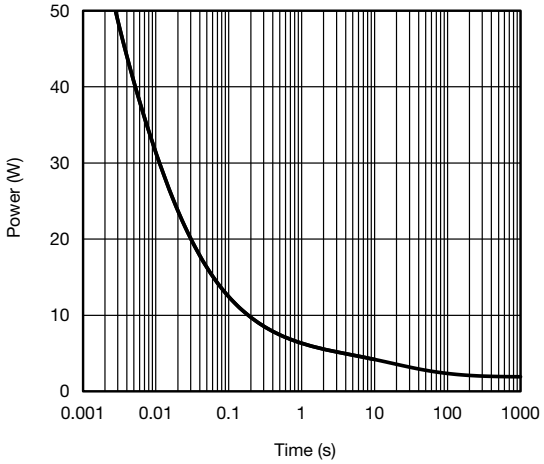
Source-Drain Diode Forward Voltage



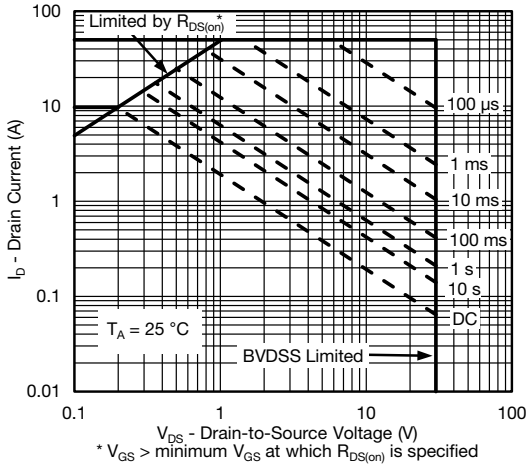
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



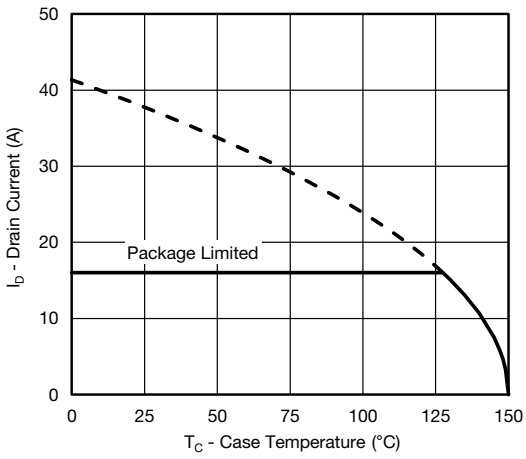
Single Pulse Power



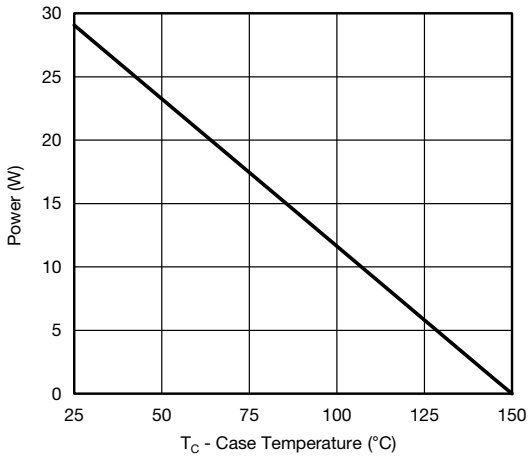
Safe Operating Area, Junction-to-Ambient

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CHANNEL-1 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating [a]



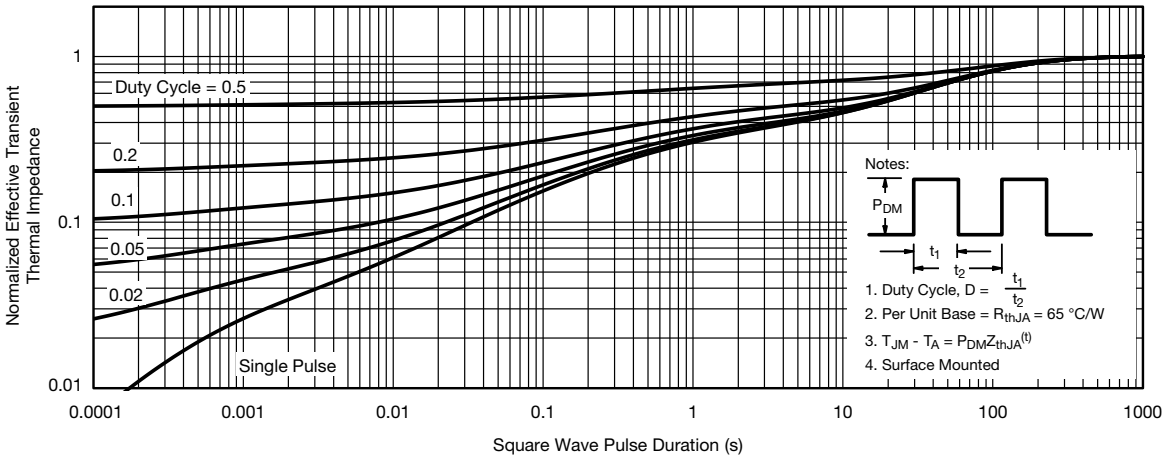
Power, Junction-to-Case

Note

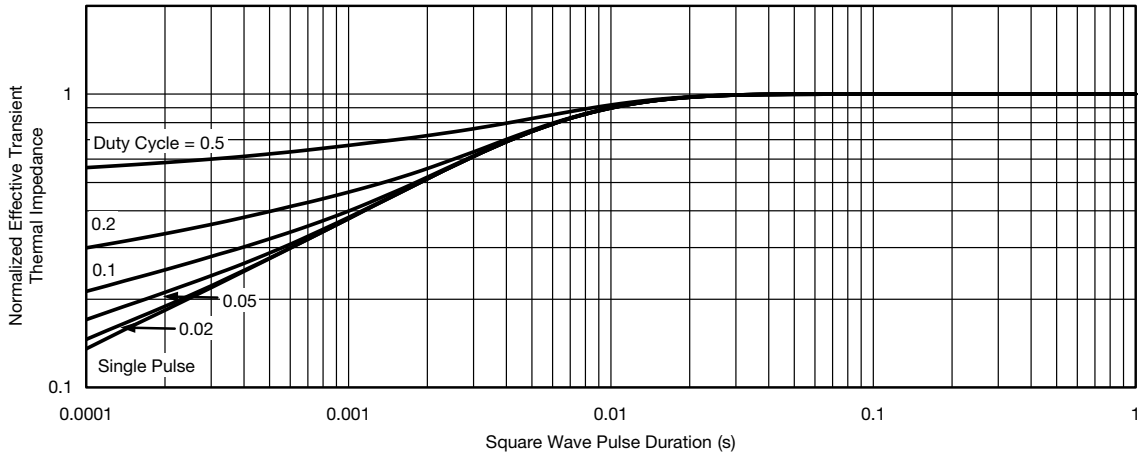
a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

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CHANNEL-1 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



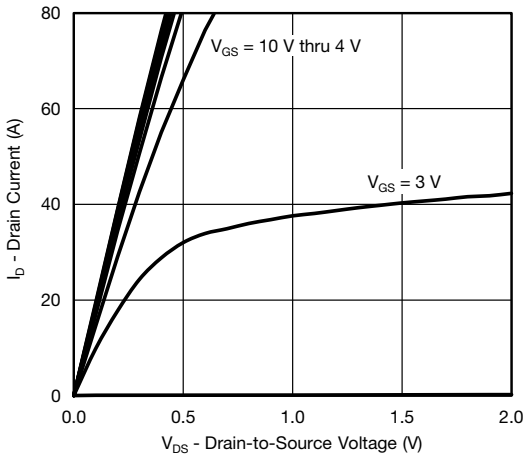
Normalized Thermal Transient Impedance, Junction-to-Ambient



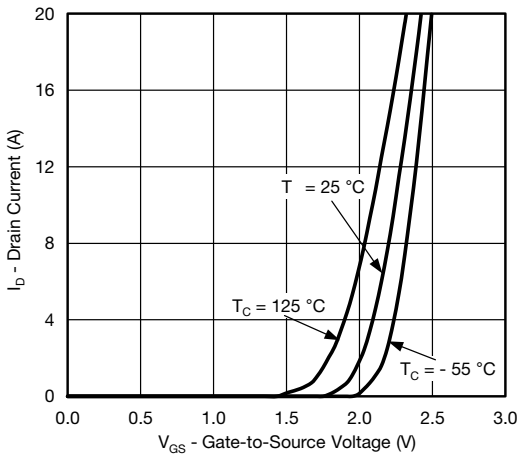
Normalized Thermal Transient Impedance, Junction-to-Case

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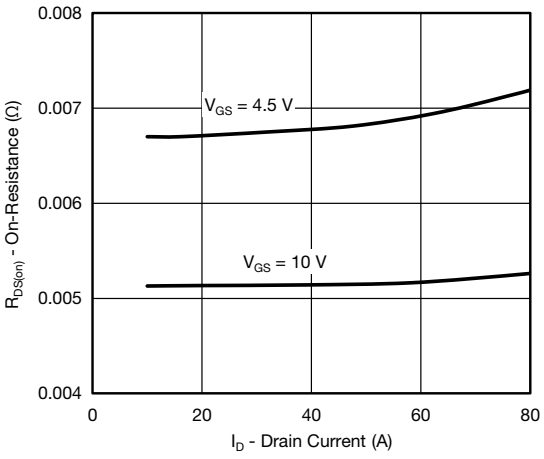
CHANNEL-2 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



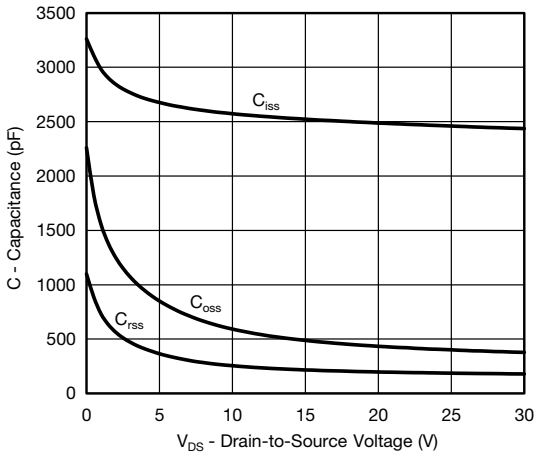
Output Characteristics



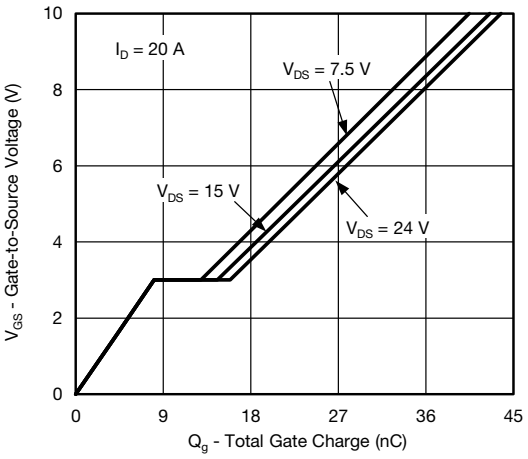
Transfer Characteristics



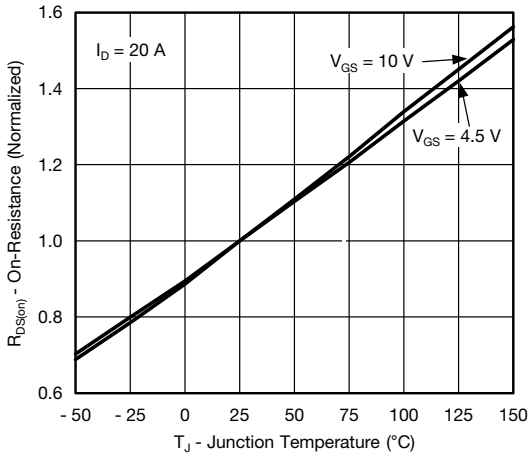
On-Resistance vs. Drain Current



Capacitance



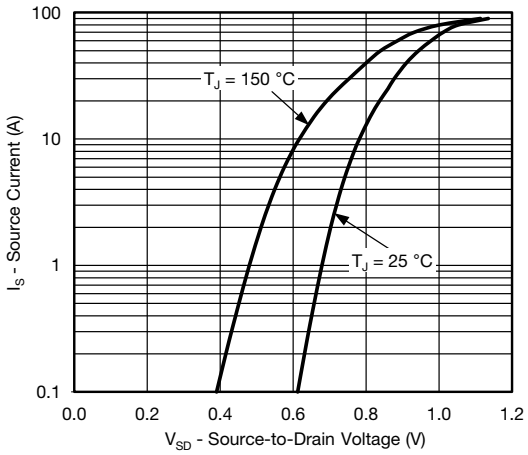
Gate Charge



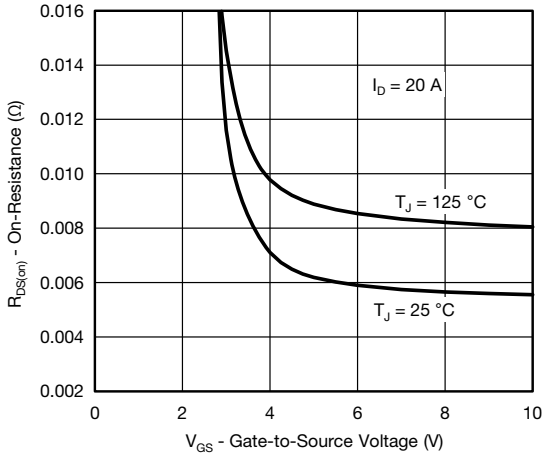
On-Resistance vs. Junction Temperature

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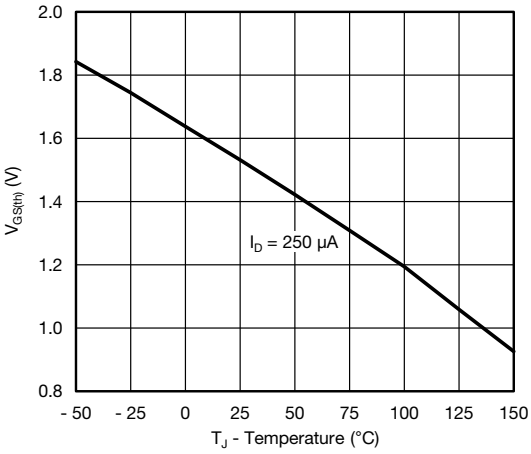
CHANNEL-2 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



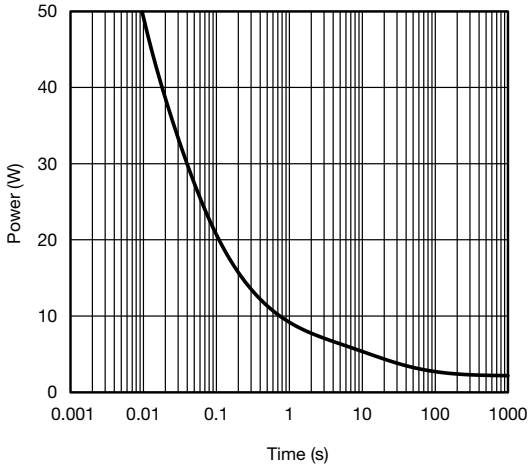
Source-Drain Diode Forward Voltage



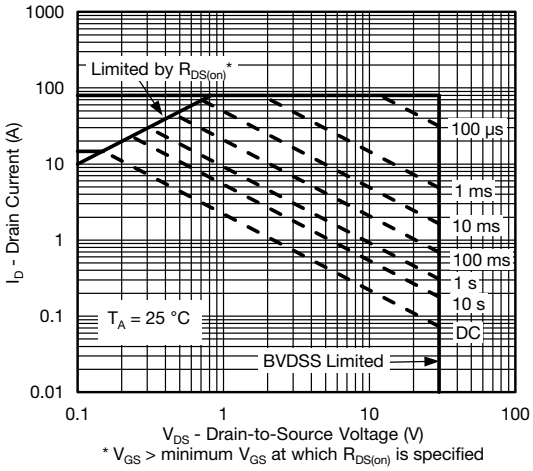
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



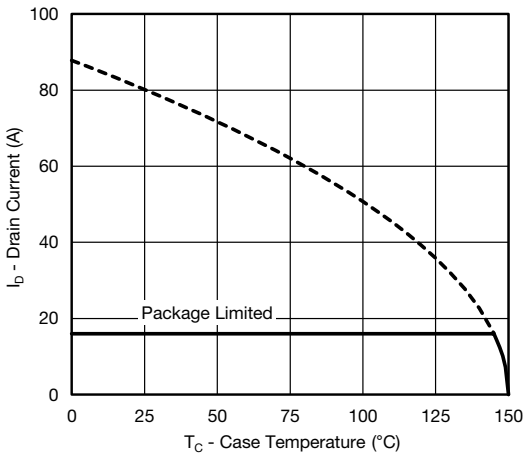
Single Pulse Power



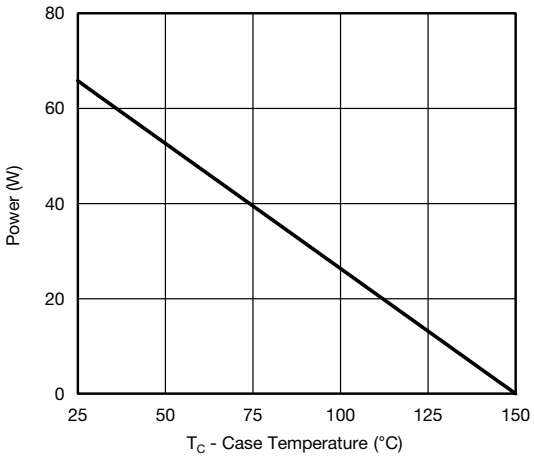
Safe Operating Area, Junction-to-Ambient

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CHANNEL-2 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating [a]



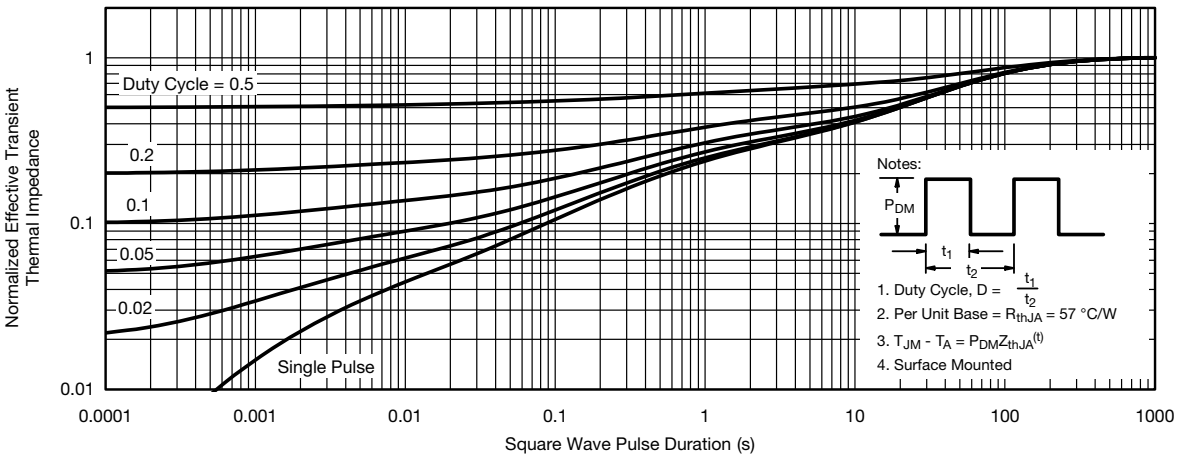
Power, Junction-to-Case

Note

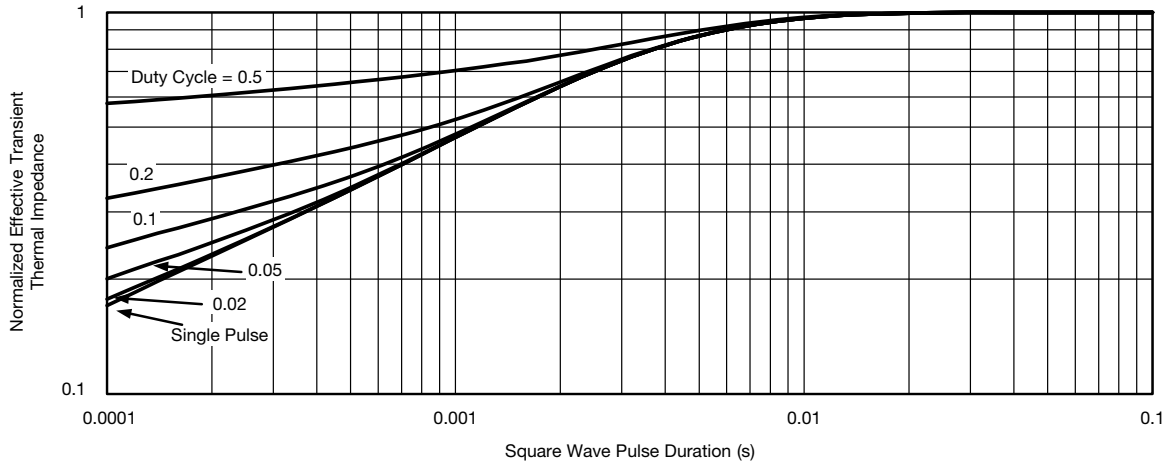
a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

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CHANNEL-2 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

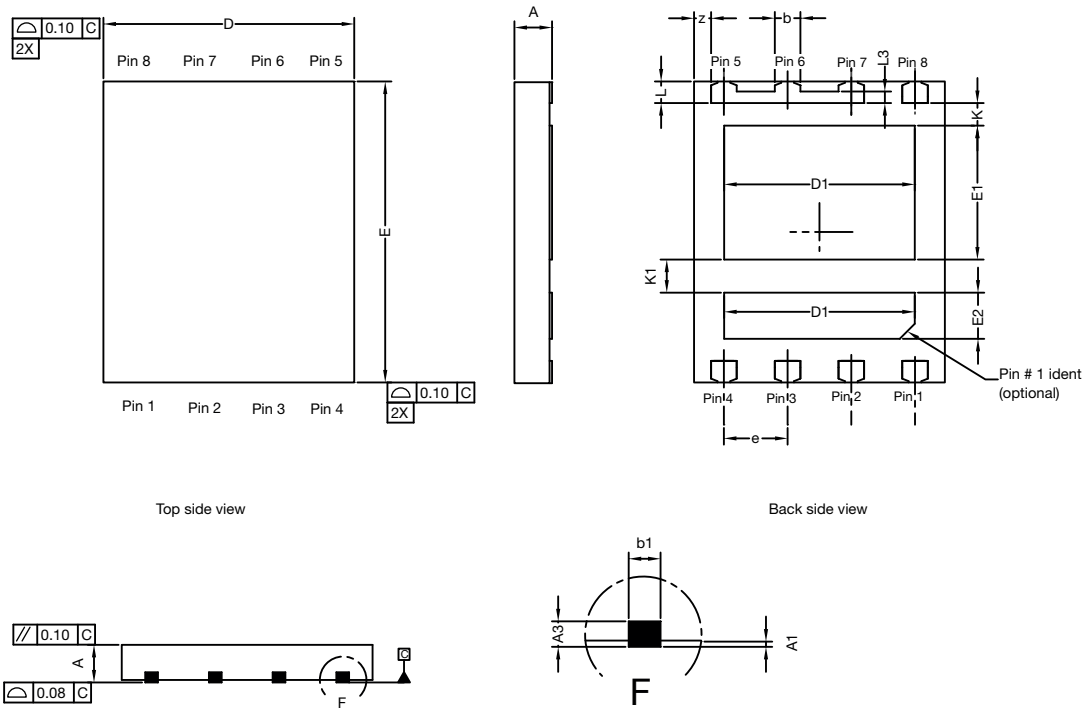


Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?63465.

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PowerPAIR® 6 x 5 Case Outline

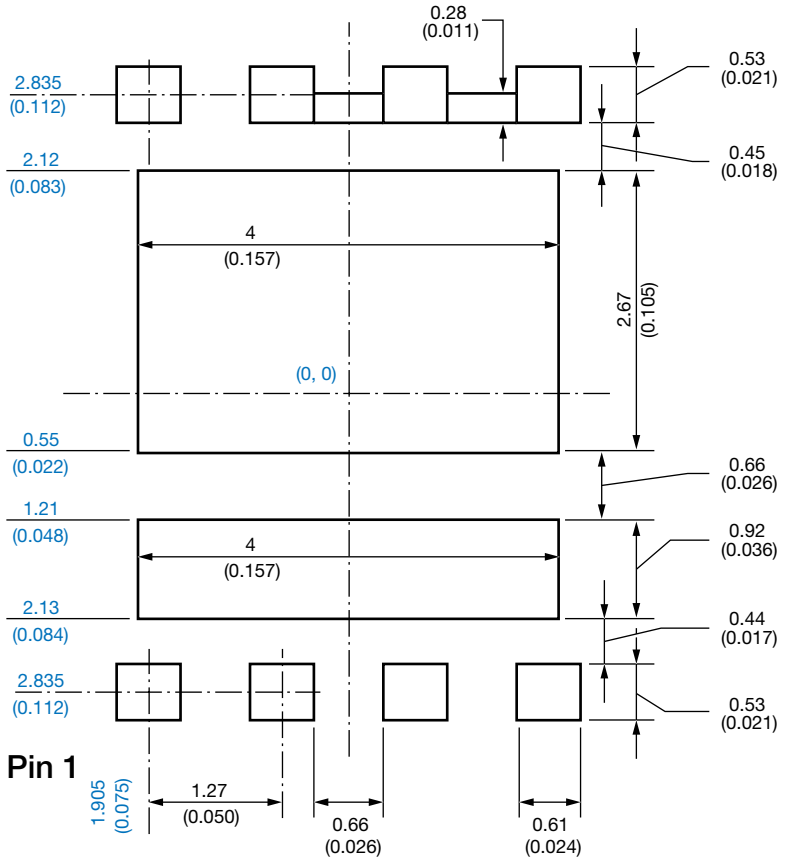


DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.70	0.75	0.80	0.028	0.030	0.032
A1	0.00	-	0.10	0.000	-	0.004
A3	0.15	0.20	0.25	0.006	0.007	0.009
b	0.43	0.51	0.61	0.017	0.020	0.024
b1		0.25 BSC			0.010 BSC	
D	4.90	5.00	5.10	0.192	0.196	0.200
D1	3.75	3.80	3.85	0.148	0.150	0.152
E	5.90	6.00	6.10	0.232	0.236	0.240
E1 Option AA (for W/B)	2.62	2.67	2.72	0.103	0.105	0.107
E1 Option AB (for BWL)	2.42	2.47	2.52	0.095	0.097	0.099
E2	0.87	0.92	0.97	0.034	0.036	0.038
e		1.27 BSC			0.050 BSC	
K Option AA (for W/B)		0.45 typ.			0.018 typ.	
K Option AB (for BWL)		0.65 typ.			0.025 typ.	
K1		0.66 typ.			0.025 typ.	
L	0.33	0.43	0.53	0.013	0.017	0.020
L3		0.23 BSC			0.009 BSC	
z		0.34 BSC			0.013 BSC	
ECN: T14-0782-Rev. C, 22-Dec-14 DWG: 6005						

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Recommended Minimum PAD for PowerPAIR® 6 x 5



Dimensions in millimeters (inch)

Note

- Linear dimensions are in black, the same information is provided in ordinate dimensions which are in blue.

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